L Number	Hits		DB	Time stamp
1	1804		USPAT	2004/01/09 09:24
2	15101	427/58-126.6.ccls.	USPAT	2004/01/09 09:24
3	58	427/58-126.6.ccls. and (epitaxial adi2	USPAT	2004/01/09 09:24
4	88369	film) (dielectric adj1 layer) or (insulating adj1 layer)	USPAT	2004/01/09 09:27
5	10	((dielectric adj1 layer) or (insulating adj1 layer)) and (427/58-126.6.ccls. and	USPAT	2004/01/09 09:34
7	1024	(epitaxial adj2 film))		
á l	1024	((texture\$5 or rough\$5) adj1 substrate)	USPAT	2004/01/09 09:35
	1	(((texture\$5 or rough\$5) adj1 substrate)) and (((dielectric adj1 layer) or (insulating adj1 layer)) and (epitaxial	USPAT	2004/01/09 09:35
6	443	adj2 film))		
	443	((dielectric adj1 layer) or (insulating adj1 layer)) and (epitaxial adj2 film)	USPAT	2004/01/09 09:41
9	206273	(fuel adj1 cell) or capacitor or SOFC	USPAT	2004/01/00 00 14
10	171	((fuel adj1 cell) or capacitor or SOFC)	USPAT	2004/01/09 09:41
		<pre>and (((dielectric adj1 layer) or (insulating adj1 layer)) and (epitaxial adj2 film))</pre>	USPAT	2004/01/09 10:01
11	4638	perovskite	USPAT	2004/01/09 10:01
12	45	perovskite and (((fuel adj1 cell) or	USPAT	2004/01/09 10:01
		capacitor or SOFC) and (((dielectric adj1		
1	1	layer) or (insulating adj1 layer)) and	1	
		(epitaxial adj2 film)))		